



30V TO252 (DPAK) N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub>	I <sub>D</sub> T <sub>A</sub> = 25°C		
30V	24mΩ @ V <sub>GS</sub> = 10V	14.4A		
	39mΩ @ V <sub>GS</sub> = 4.5V	11.6A		

# **Description and Applications**

This new generation MOSFET has been designed to minimize the onstate resistance ( $R_{DS(on)}$ ) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- DC-DC Converters
- Power management functions

## **Features and Benefits**

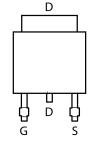
- Low on-resistance
- Fast switching speed
- Low gate drive
- "Green" component and RoHS compliant (Note 1)

# **Mechanical Data**

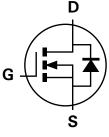
- Case: TO-252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0 (Note 1)
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals Connections: See Diagram
- Terminals: Matte Tin Finish annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Below
- Ordering Information: See Below
- Weight: 0.33 grams (approximate)



TOP VIEW



PIN OUT -TOP VIEW



Equivalent Circuit

## Ordering Information (Note 1)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMN3024LK3-13	N3024L	13	16	2,500

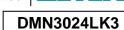
Note: 1. Diodes, Inc. defines "Green" products as those which are Eu RoHS compliant and contain no halogens or antimony compounds; further information about Diodes Inc.'s "Green" Policy can be found on our website. For packaging details, go to our website.

## **Marking Information**



>!! = Manufacturer's Marking N3024L = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 09 = 2009) WW = Week (01-52)





#### Maximum Ratings @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic			Symbol	Value	Unit	
Drain-Source voltage			VDSS	30	V	
Gate-Source voltage			V <sub>GS</sub>	±20	V	
Continuous Drain current		(Note 3)	I <sub>D</sub>	14.4		
	$V_{GS} = 10V$	T <sub>A</sub> =70°C (Note 3)		12.0	А	
		(Note 2)		9.78		
Pulsed Drain current	V <sub>GS</sub> = 10V	(Note 4)	I <sub>DM</sub>	46.5	А	
Continuous Source current (	ontinuous Source current (Body diode) (Note 3)		Is	12	A	
Pulsed Source current (Body diode) (Note 4)		I <sub>SM</sub>	46.5	А		

# Thermal Characteristics $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Value	Unit		
	(Note 2)		4.1 32.5		
Power dissipation Linear derating factor	(Note 3)	PD	8.9 71.4	W mW/°C	
	(Note 5)		2.17 17.4		
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3) (Note 5)	R <sub>θJA</sub>	30.8 14.0 57.6	°C/W	
Thermal Resistance, Junction to Lead	(Note 6)	R <sub>θJL</sub>	2.24		
Operating and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-55 to 150	٥C	

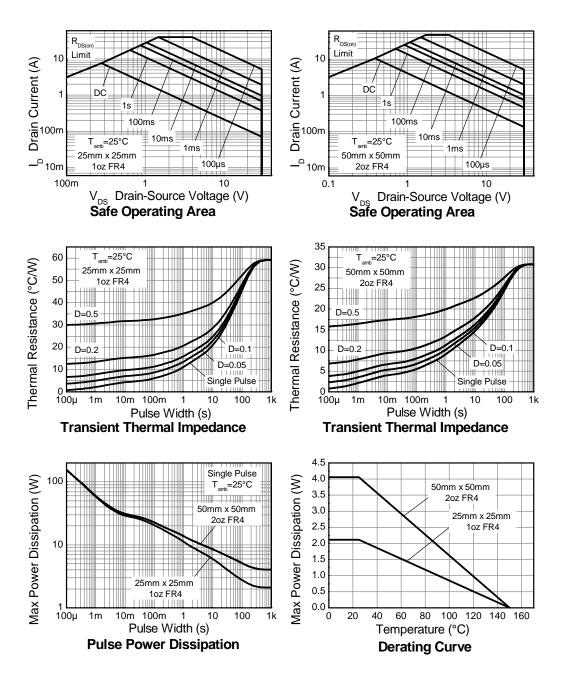
2. For a device surface mounted on 50mm x 50mm x 1.6mm FR4 PCB with high coverage of single sided 2oz copper, in still air conditions; the device is Notes: measured when operating in a steady-state condition.

3. Same as note 2, except the device is measured at t  $\leq$  10 sec. 4. Same as note 2, except the device is pulsed with D = 0.02 and pulse width 300 µs. The pulse current is limited by the maximum junction temperature. 5. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

6. Thermal resistance from junction to solder-point (at the end of the drain lead).



# **Thermal Characteristics**







# Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_	_	V	$I_D = 250 \mu A, V_{GS} = 0 V$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	0.5	μA	$V_{DS}$ = 30V, $V_{GS}$ = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V	
ON CHARACTERISTICS							
Gate Threshold Voltage	V <sub>GS(th)</sub>	1.0		3.0	V	$I_D=250\mu A$ , $V_{DS}=V_{GS}$	
Static Drain-Source On-Resistance (Note 7)	P	_	_	0.024	Ω	V <sub>GS</sub> = 10V, I <sub>D</sub> = 7.0A	
	R <sub>DS (ON)</sub>			0.039	12	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 6.0A	
Forward Transconductance (Notes 7 & 8)	<b>g</b> fs	_	16.5	_	S	V <sub>DS</sub> = 15V, I <sub>D</sub> = 7.0A	
Diode Forward Voltage (Note 7)	V <sub>SD</sub>	_	0.82	1.2	V	I <sub>S</sub> = 1.7A, V <sub>GS</sub> = 0V	
Reverse recovery time (Note 8)	t <sub>rr</sub>		12	_	ns		
Reverse recovery charge (Note 8)	Qrr	_	4.8	—	nC	I <sub>S</sub> = 2.2A, di/dt= 100A/μs	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>	_	608	—	pF		
Output Capacitance	C <sub>oss</sub>	_	132	—	pF	└V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V - f= 1MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	71	_	pF		
Total Gate Charge	Qg	_	12.9	_	nC		
Gate-Source Charge	Q <sub>gs</sub>	_	2.5	_	nC	$V_{DS}$ = 15V, $V_{GS}$ = 10V	
Gate-Drain Charge	Q <sub>gd</sub>		2.5		nC	$-I_{D}=7A$	
Turn-On Delay Time (Note 9)	t <sub>D(on)</sub>		2.9	_	ns		
Turn-On Rise Time (Note 9)	tr	_	3.3	—	ns	V <sub>DD</sub> = 15V, V <sub>GS</sub> = 10V	
Turn-Off Delay Time (Note 9)	t <sub>D(off)</sub>	—	16	_	ns	I <sub>D</sub> = 1A, R <sub>G</sub> ≅ 6.0Ω	
Turn-Off Fall Time (Note 9)	tf	_	8	_	ns	1	

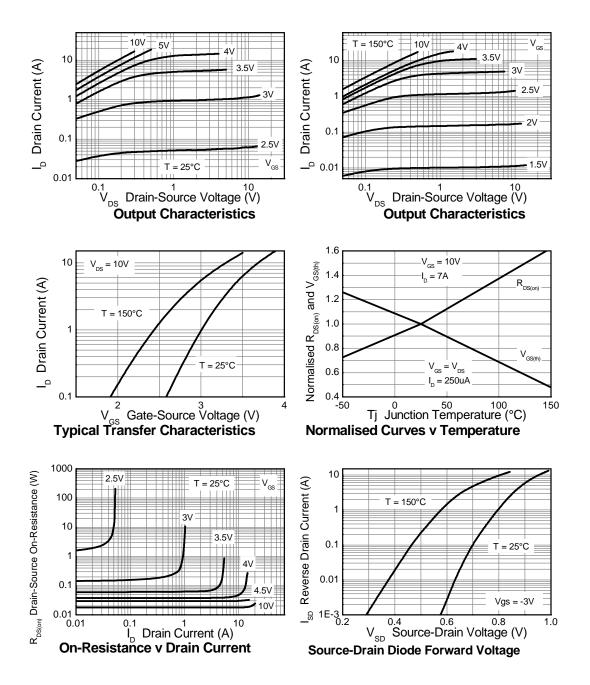
Measured under pulsed conditions. Pulse width  $\leq 300 \mu s;$  duty cycle  $\leq 2\%$ 7.

For design aid only, not subject to production testing.
Switching characteristics are independent of operating junction temperatures.

Notes:

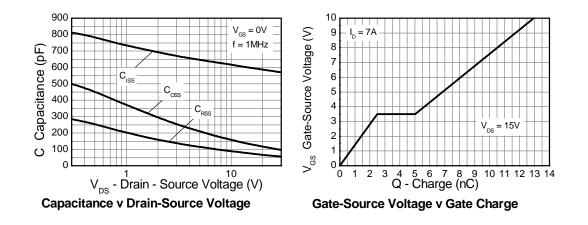


# **Typical Characteristics**

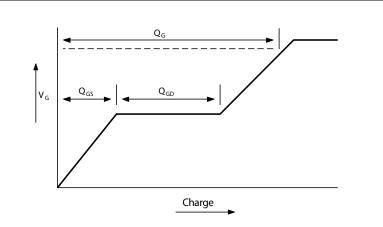




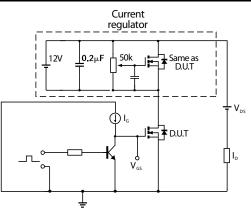
# **Typical Characteristics - continued**



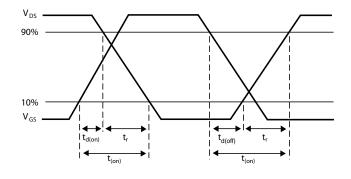
**Test Circuits** 



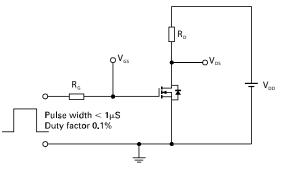
Basic gate charge waveform







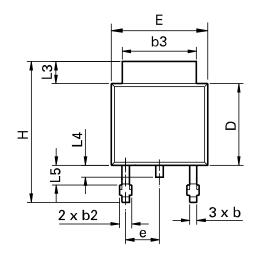
Switching time waveforms

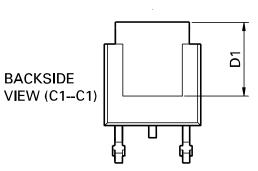


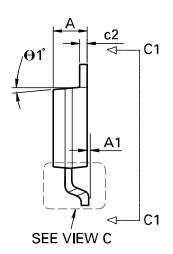
## Switching time test circuit

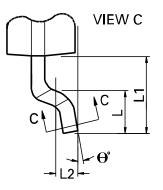


# Package Outline Dimensions





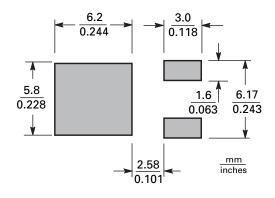




DIM	Inc	hes	Millin	neters	DIM	Inches		Millimeters	
	Min	Max	Min	Max		Min	Max	Min	Max
Α	0.086	0.094	2.18	2.39	е	0.090 BSC		2.29 BSC	
A1	-	0.005	-	0.127	н	0.370	0.410	9.40	10.41
b	0.020	0.035	0.508	0.89	L	0.055	0.070	1.40	1.78
b2	0.030	0.045	0.762	1.14	L1	0.108 REF		2.74 REF	
b3	0.205	0.215	5.21	5.46	L2	0.020 BSC		0.508 BSC	
с	0.018	0.024	0.457	0.61	L3	0.035	0.065	0.89	1.65
c2	0.018	0.023	0.457	0.584	L4	0.025	0.040	0.635	1.016
D	0.213	0.245	5.41	6.22	L5	0.045	0.060	1.14	1.52
D1	0.205	-	5.21	-	θ1°	0°	10°	0°	10°
Е	0.250	0.265	6.35	6.73	θ°	0°	15°	0°	15°
E1	0.170	-	4.32	-	-	-	-	-	-



# **Suggested Pad Layout**



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